

Supporting Information:

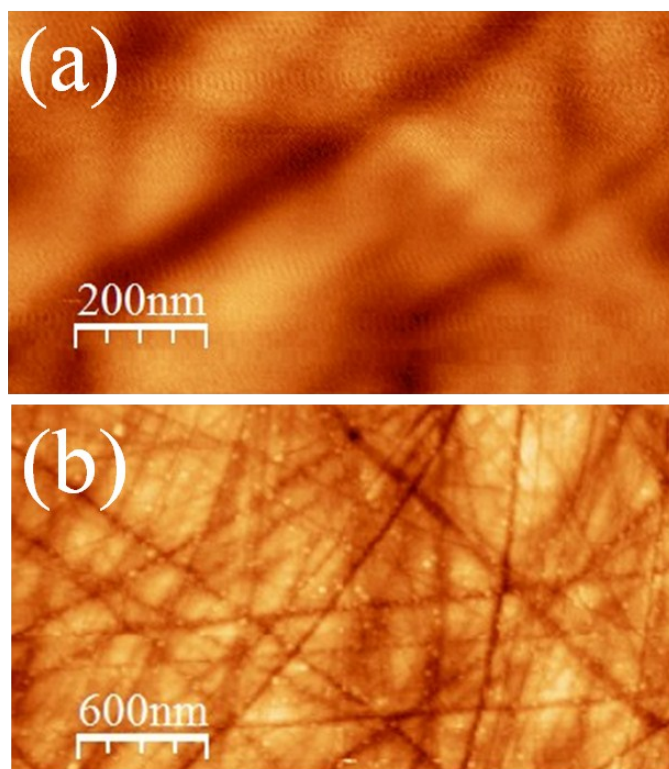


Figure S1. (a) Atomic force microscopic image of bare sapphire substrate before deposition.
(b) In nanoparticles observed to be seeded after the temperature during growth raised to 500 °C and kept for 30 minutes.

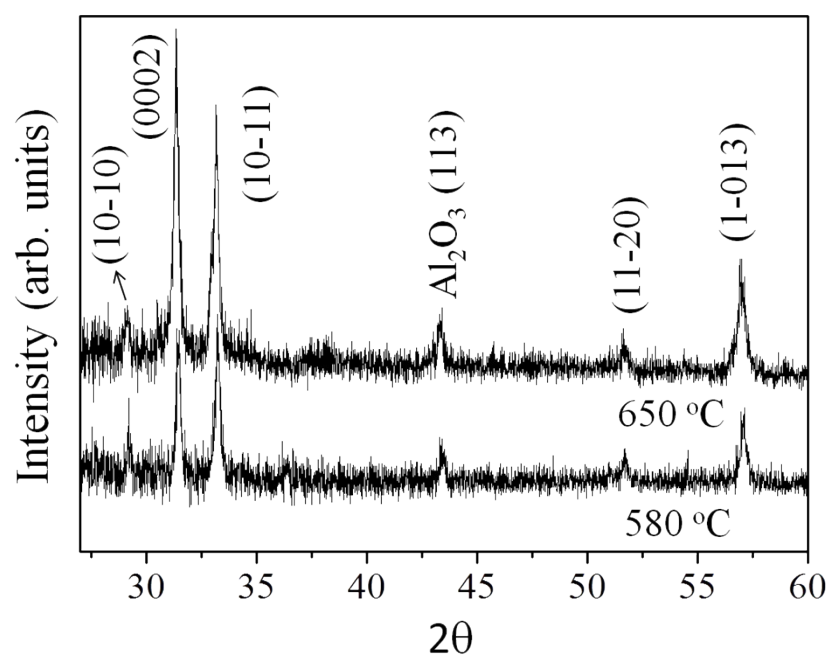


Figure S2. X-ray diffraction patterns of InN samples grown at two extreme growth temperatures of 580 and 650 °C.